FLASH Injector Laser

Laser 1

Laser 2

Next steps

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HELMHOLTZ

Max-Born-Institut Berlin Ingo Will Ingo Templin











Photocathode: work function, $QE \rightarrow$ determines wavelength, energy >

Superconducting accelerator Nong bunch traine			
$>$ Superconducting accelerator \rightarrow long burien trains			Actual specs
synchronization	<<1 dg of RF cycle	<<2 ps @1.3 GHz	< 1 ps rms
longitudinal and transverse size	~5 dg RF \rightarrow ~10 ps	field uniformity → ~mm	length 20 ps, Ø = 3 mm
charge ~1 nC per bunch	Cs ₂ Te cathode QE ~ 1…10% (UV)	∼1 µJ/pulse@UV	factor of ~10 overhead
long trains of pulses with low rep rate	trains 800 μs	long with up to 7200	pulses (9 MHz) @ 10 Hz

- \rightarrow Laser average power in the Watt range
- > Suitable type of laser \rightarrow mode-locked solid-state system (MOPA: synchronized oscillator + amplifiers + frequency converter to UV)



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Laser 1 System Overview

I. Will, G. Koss, I. Templin, NIM A 541 (2005) 467–477





MBI

Pulse Train Oscillator (PTO) – same for both lasers



> Mode-locked pulsed oscillator

- Diode pumped (32 W)
- Synchronized to 1.3 GHz master oscillator
 - 1.3 GHz EO modulator with 2 AOMs (108 + 13.5 MHz)
 - Phase stability < 200 fs rms</p>
 - Pulse length 12 ps (fwhh) IR -> 10 ps UV
- Stabilized with quartz rods
 - Thermal expansion coefficient
 fused quartz = 0.59 ppm/K (AI = 24 ppm/K)
- > 27 MHz pulse train
 - Train length 2.5 ms, pulsed power 7 W





Laser 1: Chain of Linear Amplifiers

> 2 diode pumped and 2 flashlamp pumped single pass amplifiers

- > Flashlamps pumped heads:
 - \rightarrow cheap, powerful (pulsed, 50 kW electrical/head)
 - \rightarrow current control with high power IGPT switches
 - \rightarrow allows flat pulse trains
 - \rightarrow energy up to 300 µJ (1 MHz), 140 µJ (3 MHz)
 - \rightarrow small-signal gain = 20
 - \rightarrow extractable peak power 1.2 kW, duty cycle 2%

Laser diodes: \rightarrow 32 W pulsed, 805 nm, laser 2: 100 W diodes \rightarrow end pumped through fibers

> Xe flashlamps Nd:YLF rod, Ø 5 or 7 mm

 \rightarrow energy from 0.3 µJ to 6 µJ/pulse

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- 5 mm

Pulse Trains

- > 2 Pulse pickers, based on Pockels cell + polarizer \rightarrow 1 MHz
- > Pre-amplification (diodes) of 1.2 ms long train
- > Power amplification with variable bunch pattern

FLASH design goals reached in 2007

Lasing with a complete bunch train of 800 bunches at 13.4 nm

GMD - gas monitor detector - signal

Bunch Pattern and MPS

- > Change bunch pattern on user request
 - Number of bunches
 - Different bunch frequencies: 1 MHz, 500 kHz, 250 kHz, 100 kHz and others
- Realized with an FPGA based controller producing the appropriate trigger for the Pockels cell
- > New card for laser 2 (T. Schulz)
- The controller is also the interface of the machine protection system to the laser

Laser 2 – fully diode pumped

- > Has been extensively operated at PITZ
- > FLASH version without pulse shaper, but with 3 MHz option (5 Hz only)

- > 6 stage amplification including one double pass
- > Power amplifiers pumped with 100 W laser.diodesFLASH Meeting | 16-Nov-2009

Diode-pumped Nd:YLF laser at FLASH was upgraded to 3 MHz repetition rate

- New: Reliable 3 MHz pulse selectors driven by high-voltage power MOSFETs
- Average power of the laser was increased by:
 - Optimization of the optical layout of the amplifier chain
 - Two optimized protection systems allow operating the laser at higher intensity
- Results
 - Improved stability and reliability
 - Simplified maintenance: Fully diode-pumped system, No exchange of flashlamps required.

- Limit of the current laser:
 - 3 MHz / 5 Hz or
 - 1 MHz / 10 Hz
- XFEL mode (5 MHz / 10 Hz) needs:
 - Redesign of the laser heads and of the optical layout of the laser
 - Stronger pump diodes
 - Improved Pockels cell drivers

3 MHz Pockels cell drivers

Laser Beamline

- > Relay imaging with spatial filtering
- > Hard edge aperture after diode pumped amplifiers
- > Aperture imaged to \rightarrow amplifier heads \rightarrow doubling crystals \rightarrow cathode

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Transverse Shape

- > Shape depends on quality of doubling process
- Irregular shape at laser 1, hard edge iris always required
- > BBO already exchanged twice, new crystals ordered

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Laser 2 transverse shape

With iris in front of vacuum window

- With additional magnification by 2 (total ~10) >
- Very good pointing stability, paid with fringes (~20% modulation) >

Nominal iris 2.5 mm diameter

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Laser

Table Iris on cathode

- > Imaging the overfilled iris on laser table
- > Problem: larger pointing jitter than iris in front of vacuum window

Distance iris – telescope wrong by ~1 cm

Distance iris - telescope correct

Laser Pulse Length and Shape

- > Both lasers have the same longitudinal gaussian shape
- > Laser 1: Measurement with a streak camera (FESCA 200) $\sigma_L = 4.4 \pm 0.1 \text{ ps} (\text{at } 262 \text{ nm})$

- R&D laser at PITZ: Longitudinal flat-hat shape
- > Works fine in 'lab environment', not mature yet for a user facility
- > To some extend flexible pulse shapes
 - Pulse can be made shorter, even gaussian
 - With Lyot filters smoothening of edges and flattop

> Laser 1 charge stability 1 % rms

Laser 2: Charge Stability

> Laser 2 charge stability better than 1 % rms

Phase Stability

- > Phase stability measured with improved rf gun calibration
- Stability laser 1: 0.08 dg (170 fs) laser 2: 0.04 dg (84 fs)
- > no pattern in reflected power measured
- > both measurement within 1.5 h
- > Remote diagnostics and control of phases is being installed (R. Jonas)
- Integration into synchronization system in preparation

1 dg of 1.3 GHz = 2.1 ps

Laser Mirror Quality

- > Issue with halo creation and profile quality observed at PITZ for some mirrors
- We started again an effort to find new suppliers and to set-up a quality control test stand

Laser Mirror in the Diagnostics Cross

- Next upgrade will be to install the diode pumped amplifiers of the previous PITZ laser to replace the flashlamp pump heads of laser 1
- > Once a flat-hat laser has been extensively tested at PITZ, we will install a flat-hat version at FLASH
- MoU with Max-Born-Institute on the development of the XFEL injector laser and upgrades for PITZ and FLASH
- Soal is to have a working system meeting the XFEL specs in 2012
- Main issue now is to combine the flat-hat shape feature with a 5 MHz intra-bunch repetition rate

UV output pulses of the laser

Shape of the micropulses measured with optical sampli system

Generating flat-top laser pulses by means of a multi crystal birefringent pulse shaper

Optical setup

МЗІ

Installed at PITZ: N = 13 crystals